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PATENT NUMBER and
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U.S. UTILITY Patent Application

APPL NUM 10030867	FILING DATE 04/29/2002	CLASS 117	SUBCLASS 1	GAU 1765	EXAMINER J. J. G. W. M.
**APPLICANTS: Kimura Masanori;					
**CONTINUING DATA VERIFIED: THIS APPLICATION IS A 371 OF PCT/JP01/01125 02/16/2001					
** FOREIGN APPLICATIONS VERIFIED: JAPAN 2000-044422 02/22/2000					
PG-PUB <input type="checkbox"/> DO NOT PUBLISH <input type="checkbox"/>		RESCIND <input type="checkbox"/>			
Foreign priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no		35 USC 119 conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no		ATTORNEY DOCKET NO 81839.0105	
Verified and Acknowledged Examiners's initials <i>MM</i>					
TITLE : Method for growing single crystal of semiconductor					
U.S. DEPT. OF COMM./PAT & TM-PTO-436L(Rev. 12-94)					

NOTICE OF ALLOWANCE MAILED		Assistant Examiner	CLAIMS ALLOWED	
			Total Claims	Print Claim for O.G.
ISSUE FEE		Primary Examiner	DRAWING	
Amount Due	Date Paid		Sheets Drwg.	Figs. Drwg.
<input type="checkbox"/> TERMINAL DISCLAIMER		PREPARED FOR ISSUE	Application Examiner	
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